



**MOTOROLA**

**MDA1200 MDA1201  
MDA1202 MDA1204  
MDA1206**

**Designers Data Sheet**

**FULL-WAVE BRIDGE RECTIFIER ASSEMBLIES**

...utilizing individual MR2500 Series plastic button rectifiers interconnected and then enclosed in plastic to provide a single rugged package. Devices are available with voltages from 50 to 600 Volts with these additional features.

- Slip-on Terminals
- High Surge Capability
- Output Current Ratings for both Case and Ambient Conditions

**Designers Data for "Worst Case" Conditions**

The Designers Data sheets permit the design of most circuits entirely from the information presented. Limit curves—representing boundaries on device characteristics—are given to facilitate "worst case" design.

**MAXIMUM RATINGS**  $T_C = 25^\circ\text{C}$  unless otherwise noted.

Rating	Symbol	MDA 1200	MDA 1201	MDA 1202	MDA 1204	MDA 1206	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	50	100	200	400	600	Volts
RMS Reverse Voltage	$V_R(\text{RMS})$	35	70	140	280	420	Volts
DC Output Voltage	$V_{dc}$						Volts
Resistive Load		30	62	124	250	380	
Capacitive Load		50	100	200	400	600	
Average Rectified Forward Current (Single-phase bridge, resistive load 60 Hz) $T_A = 55^\circ\text{C}$ (unmounted) $T_A = 55^\circ\text{C}$ (7" x 7" AL Chassis) $T_C = 100^\circ\text{C}$	$I_O$						Amp
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions)	$I_{FSM}$						Amp
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$						$^\circ\text{C}$

**THERMAL CHARACTERISTICS**

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	Each Die	$R_{\theta JA}$	28 $^\circ\text{C}/\text{W}$
	Effective Bridge	$R_{\theta JA}(\text{EFF})$	17.15 $^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	Each Die	$R_{\theta JC}$	10 $^\circ\text{C}/\text{W}$
	Effective Bridge	$R_{\theta JC}(\text{EFF})$	3.75 $^\circ\text{C}/\text{W}$

**ELECTRICAL CHARACTERISTICS**  $T_C = 25^\circ\text{C}$  unless otherwise noted.

Characteristic	Symbol	Typ	Max	Unit
Instantaneous Forward Voltage (Per Diode) (1) ( $I_F = 18.9 \text{ A}$ ) ( $I_F = 18.9 \text{ A}, T_J = 175^\circ\text{C}$ )	$V_F$	0.94	1.05	Volts
Reverse Current (Rated $V_R$ applied to ac terminals, + and - terminals open)	$I_R$	—	0.5	mA

(1) Pulse Test: Pulse Width  $\leq 300 \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

**MECHANICAL CHARACTERISTICS**

**CASE** Transfer molded plastic case

**POLARITY** Terminal designation embossed on case

— DC output      + DC output      — AC not marked

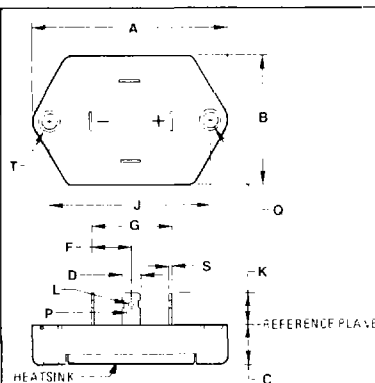
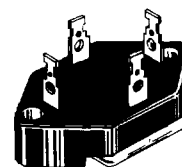
**MOUNTING POSITION:** Any. Highest heat transfer efficiency accomplished through the surface opposite the terminals.

**WEIGHT:** 41 grams (approx.)

**TERMINALS** Ready solderable, corrosion resistant, suitable for slip-on terminals.

**SINGLE-PHASE  
FULL-WAVE BRIDGE**

**12 AMPERE  
50 thru 600 VOLTS**



**NOTE**

1. MOUNTING HOLES WITHIN 0.25 mm (0.010) DIA OF TRUE POSITION AT MAXIMUM MATERIAL CONDITION.
2. COUNTERSUNK MOUNTING HOLES FOR 321 02 ONLY 3/16 (125) DEEP.
3. DIMENSIONS F AND G SHALL BE MEASURED AT THE REFERENCE PLANE.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	53.98	55.12	2.125	2.170
B	34.80	35.18	1.370	1.385
C	12.45	13.49	0.490	0.531
D	5.10	6.60	0.240	0.260
F	14.00	14.50	0.550	0.571
G	28.00	29.00	1.100	1.142
J	42.94	BSC	1.730	BSC
K	9.52	11.43	0.375	0.450
L	1.52	2.06	0.060	0.081
P	2.79	2.52	0.110	0.115
Q	3.81	4.32	0.150	0.170
S	0.71	0.86	0.028	0.034

CASE 321 01

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# MDA1200, MDA1201, MDA1202, MDA1204, MDA1206

FIGURE 1 – FORWARD VOLTAGE

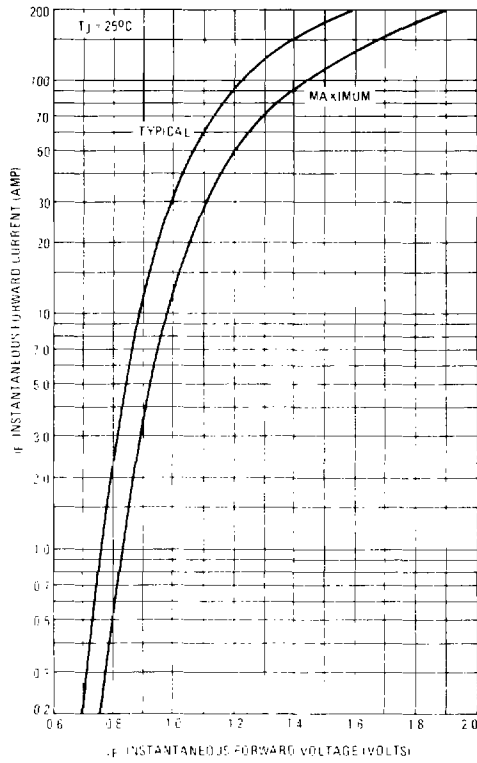


FIGURE 2 – NON-REPETITIVE SURGE CURRENT

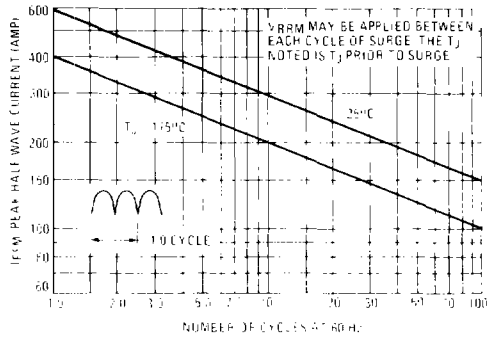


FIGURE 3 – FORWARD VOLTAGE TEMPERATURE COEFFICIENT

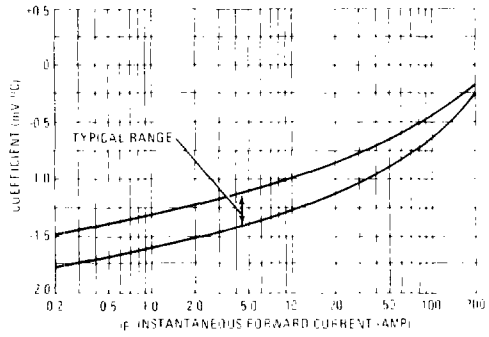
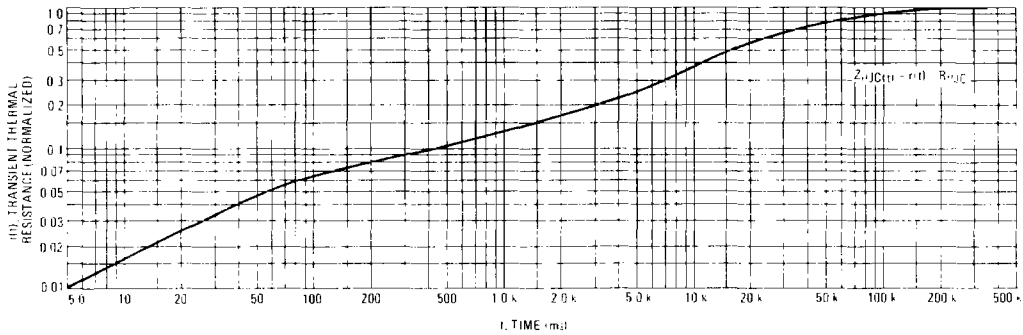


FIGURE 4 – TYPICAL THERMAL RESPONSE



MAXIMUM CURRENT RATINGS, BRIDGE OPERATION

FIGURE 5 - AMBIENT TEMPERATURE DERATING

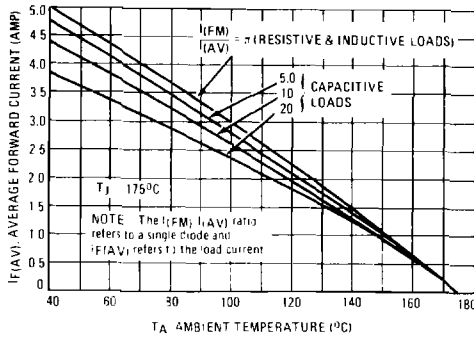
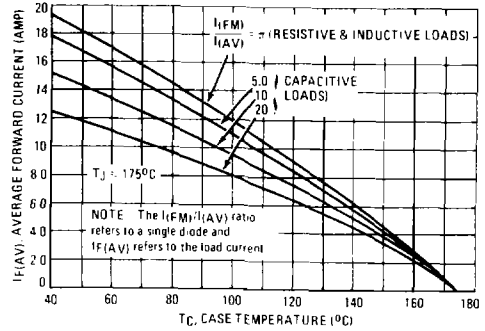


FIGURE 6 - CASE TEMPERATURE DERATING



TYPICAL DYNAMIC CHARACTERISTICS (EACH DIODE)

FIGURE 7 - RECTIFICATION WAVEFORM EFFICIENCY

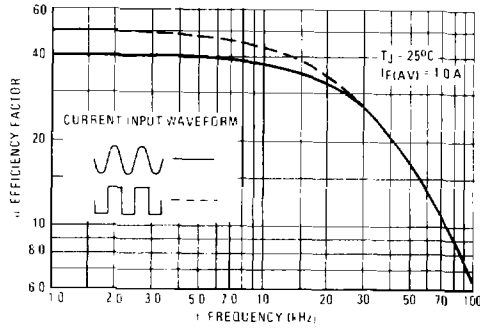


FIGURE 8 - CAPACITANCE

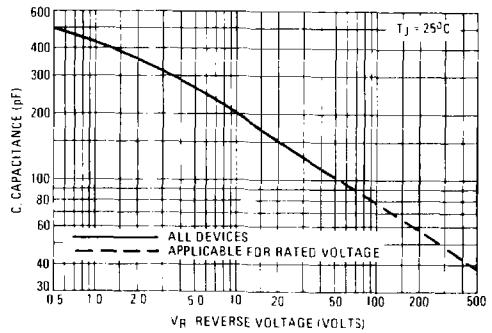


FIGURE 9 - REVERSE RECOVERY TIME

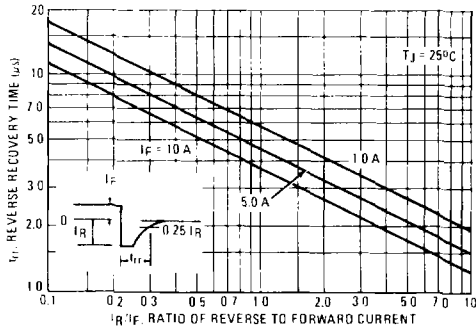


FIGURE 10 - FORWARD RECOVERY TIME

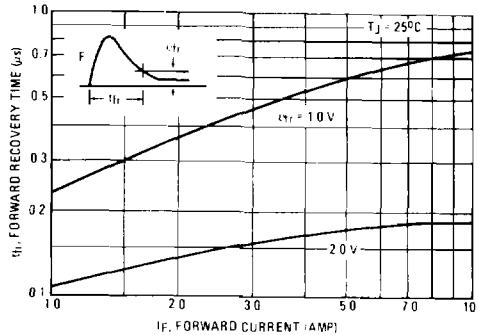
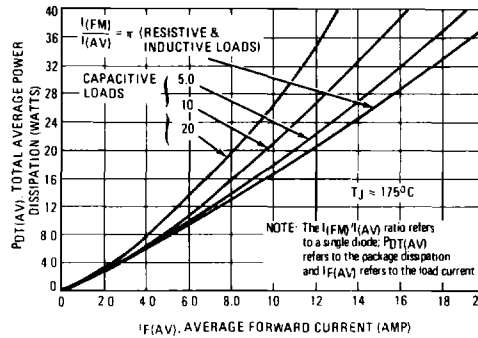


FIGURE 11 – POWER DISSIPATION



NOTE 1 – THERMAL COUPLING AND EFFECTIVE THERMAL RESISTANCE

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In multiple chip devices where there is coupling of heat between die, the junction temperature can be calculated as follows

$$(1) \Delta T_{J1} = R_{\theta 1} P_{D1} + R_{\theta 2} K_{\theta 2} P_{D2} + R_{\theta 3} K_{\theta 3} P_{D3} + R_{\theta 4} K_{\theta 4} P_{D4}$$

Where  $\Delta T_{J1}$  is the change in junction temperature of diode 1

$R_{\theta 1}$  thru 4 is the thermal resistance of diodes 1 through 4

$P_{D1}$  thru 4 is the power dissipated in diodes 1 through 4

$K_{\theta 2}$  thru 4 is the thermal coupling between diode 1 and diodes 2 through 4

An effective package thermal resistance can be defined as follows

$$(2) R_{\theta(EFF)} = \Delta T_{J1} / P_{DT}$$

Where:  $P_{DT}$  is the total package power dissipation.

Assuming equal thermal resistance for each die, equation (1) simplifies to

$$(3) \Delta T_{J1} = R_{\theta 1} (P_{D1} + K_{\theta 2} P_{D2} + K_{\theta 3} P_{D3} + K_{\theta 4} P_{D4})$$

For the condition where  $P_{D1} = P_{D2} = P_{D3} = P_{D4}$ ,  $P_{DT} = 4P_{D1}$  equation (3) can be further simplified and by substituting into equation (2) results in

$$(4) R_{\theta(EFF)} = R_{\theta 1} (1 + K_{\theta 2} + K_{\theta 3} + K_{\theta 4}) / 4$$

For the MDA1200 rectifier assembly, thermal coupling between opposite diodes is 10% and between adjacent diodes is 20% when the case temperature is used as a reference. Similarly for ambient mounting, thermal coupling between opposite diodes is 45% and between adjacent diodes is 50%.

NOTE 2 – SPLIT LOAD DERATING INFORMATION

Bridge rectifiers are used in two basic configurations as shown in circuits A and B of Figure 12. The current derating data of Figures 5 and 6 apply to the standard bridge circuit (A) where  $I_A = I_B$ . For circuit B where  $I_A \neq I_B$ , derating information can be calculated as follows

$$(5) T_{R(MAX)} = T_{J(MAX)} - \Delta T_{J1}$$

Where  $T_{R(MAX)}$  is the reference temperature (either case or ambient)

$T_{J1}$  can be calculated using equation (3) in Note 1

For example, to determine  $T_{C(MAX)}$  for the MDA1200 with the following capacitive load conditions:

$I_A = 10$  A average with a peak of 46 A

$I_B = 5.0$  A average with a peak of 35 A

First calculate the peak to average ratio for  $I_A$ ,  $I(FM)/I(AV) = 46/5.0 = 9.2$ . (Note that the peak to average ratio is on a per diode basis and each diode provides 5.0 A average).

From Figure 11, for an average current of 10 A and an  $I(FM)/I(AV) = 9.2$  read  $P_{DT}(AV) = 21$  watts or 5.25 watts/diode. Thus  $P_{D1} = P_{D3} = 5.25$  watts.

Similarly, for a load current  $I_B$  of 5.0 A, diode #2 and diode #4 each see 2.5 A average resulting in an  $I(FM)/I(AV) = 1.4$ .

Thus, the package power dissipation for 5.0 A is 10 watts or 2.5 watts/diode.  $P_{D2} = P_{D4} = 2.5$  watts.

The maximum junction temperature occurs in diodes #1 and #3. From equation (3) for diode #1  $\Delta T_{J1} = 10 [5.25 + 0.1(2.5) + 0.2(5.25) + 0.2(2.5)]$ .

$$\Delta T_{J1} \approx 70^\circ C$$

$$\text{Thus } T_{C(MAX)} = 175 - 65 = 105^\circ C$$

The total package dissipation in this example is

$$P_{DT} = 2 \times 5.25 + 2 \times 2.5 = 15.5 \text{ watts}$$

FIGURE 12 – BASIC CIRCUIT USES FOR BRIDGE RECTIFIERS

